## NSN 5961-01-147-3362

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-147-3362 **Inclosure Material:** Metal and glass **Overall Length:** 1.453 inches **Function For Which Designed:** Rectifier **End Application:** 6130-01-141-2807 **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 reverse voltage, instantaneous and 35.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 120.00 amperes forward current, average blank and 800.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 19207-12310454 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** No

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